

RCE/2819
V#

PTO/SB/30 (08-00)

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**REQUEST FOR
CONTINUED EXAMINATION (RCE)
TRANSMITTAL**

Subsection (b) of 35 U.S.C. § 132, effective on May 29, 2000,
provides for continued examination of an utility or plant application
filed on or after June 8, 1995.
See The American Inventors Protection Act of 1999 (AIPA).

Application Number	09/362,192
Filing Date	July 28, 1999
First Named Inventor	Shunpei YAMAZAKI
Group Art Unit	2812
Examiner Name	V. Simkovic
Attorney Docket Number	740756-2011

This is a Request for Continued Examination (RCE) under 37 C.F.R. § 1.114 of the above-identified application.

NOTE: 37 C.F.R. § 1.114 is effective on May 29, 2000. If the above-identified application was filed prior to May 29, 2000, applicant may wish to consider filing a continued prosecution application (CPA) under 37 C.F.R. § 1.53(d) (PTO/SB/29) instead of a RCE to be eligible for the patent term adjustment provisions of the AIPA. See Changes to Application Examination and Provisional Application Practice, Final Rule, 65 Fed. Reg. 50092 (Aug. 16, 2000); Interim Rule, 65 Fed. Reg. 14865 (Mar. 20, 2000), 1233 Off. Gaz. Pat. Office 47 (Apr. 11, 2000), which established RCE practice.

1. **Submission required under 37 C.F.R. § 1.114**

- a. ☐ Previously submitted
- i. ☐ Consider the amendment(s)/reply under 37 C.F.R. § 1.116 previously filed on _____
(Any unentered amendment(s) referred to above will be entered).
- ii. ☐ Consider the arguments in the Appeal Brief or Reply Brief previously filed on _____
- iii. ☐ Other _____
- b. ☒ Enclosed
- i. ☒ Amendment/Reply
- ii. ☐ Affidavit(s)/Declaration(s)
- iii. ☒ Information Disclosure Statement (IDS)
- iv. ☒ Other Petition for Extension of Time (for one month)

2. **Miscellaneous**

- a. ☐ Suspension of action on the above-identified application is requested under 37 C.F.R. § 1.103(c) for a period of _____ months. (Period of suspension shall not exceed 3 months; Fee under 37 C.F.R. § 1.17(l) required)
- b. ☐ Other _____

3. **Fees** The RCE fee under 37 C.F.R. § 1.17(e) is required by 37 C.F.R. § 1.114 when the RCE is filed.

- a. ☒ The Director is hereby authorized to charge the following fees, or credit any overpayments, to Deposit Account No. 19-2380
- i. ☒ RCE fee required under 37 C.F.R. § 1.17(e)
- ii. ☒ Extension of time fee (37 C.F.R. §§ 1.136 and 1.17)
- iii. ☐ Other _____
- b. ☒ Check in the amount of \$940.00 is enclosed
- c. ☐ Payment by credit card (Form PTO-2038 enclosed)

SIGNATURE OF APPLICANT, ATTORNEY, OR AGENT REQUIRED

Name (Print/Type)	Luan C. Do	Registration No. (Attorney/Agent)	38,434
Signature		Date	February 11, 2002

CERTIFICATE OF MAILING OR TRANSMISSION

I hereby certify that this correspondence is being deposited with the United States Postal Service with sufficient postage as first class mail in an envelope addressed to: Commissioner For Patents, Box RCE, Washington, DC 20231, or facsimile transmitted to the U.S. Patent and Trademark Office on:

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PATENT
740756-2011

THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re PATENT application of:

Shunpei YAMAZAKI et al.

Application No.: 09/362,192

Filed: July 28, 1999

For: SEMICONDUCTOR DEVICE HAVING
SEMICONDUCTOR CIRCUIT
COMPRISING SEMICONDUCTOR
ELEMENT AND METHOD FOR
MANUFACTURING THE SAME

Art Unit: 2812

Examiner: V. SIMKOVIC

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AMENDMENT

Commissioner of Patents
Washington, D.C. 20231

February 11, 2002

Dear Sir:

In response to the Examiner's final Office Action mailed October 11, 2001, please note that an RCE is filed herewith and consider the following amendments and remarks in connection with the above-identified application.

IN THE CLAIMS:

Please amend claims 45-50, 52-54, 56, 58, 60-62, 64 and 65 to read as follows:

45. (Amended) A method for manufacturing a semiconductor device comprising steps

of:

contacting a material for promoting crystallization to at least a part of a semiconductor film formed over a substrate;

subjecting said semiconductor film to oxygen plasma, thereby a gate insulating film is formed on said semiconductor film; and

crystallizing said semiconductor film subjected to the oxygen plasma to obtain a crystalline semiconductor film.

46. (Amended) A method according to claim 45, wherein said crystallizing is performed by crystallizing said semiconductor film by irradiating with one of an infrared ray